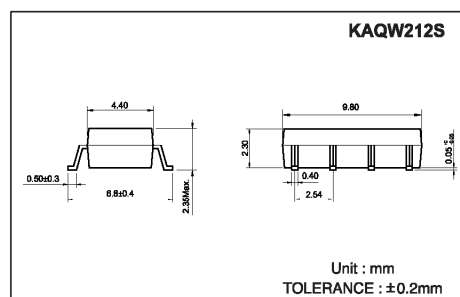


Features

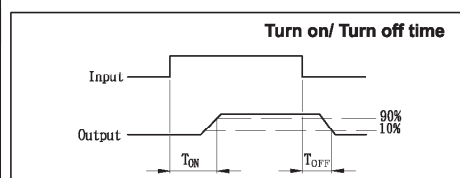
1. Normally Open, Single Pole Single Throw
2. Control 60V AC or DC Voltage
3. Switch 400mA Loads
4. LED control Current, 5mA
5. Low ON-Resistance
6. dv/dt , >500V/ms
7. Isolation Test Voltage, 1500VACrms



Absolute Maximum Ratings

(Ta=25°C)

Emitter (Input)	Detector (Output)
Reverse Voltage.....5.0V	Output Breakdown Voltage±60V
Continuous Forward Current50mA	Continuous Load Current±400mA
Peak Forward Current1A	Power Dissipation500mW
Power Dissipation100mW	
Derate Linearly from 25°C1.3mW/°C	
General Characteristics	
Isolation Test Voltage1500VACrms	Storage Temperature Range ...-40°C to +150°C
Isolation Resistance	Operating Temperature Range...-30°C to +85°C
Vio=500V, Ta=25°C≥10 ¹⁰ Ω	Junction Temperature.....100°C
Total Power Dissipation550mW	Soldering Temperature,
Derate Linearly from 25°C2.5mW/°C	2mm from case, 10 sec260°C



Electro-optical Characteristics

(Ta=25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Emitter (Input)						
Forward Voltage	V_F	$I_F = 10mA$		1.2	1.5	V
Operation Input Current	I_{FON}	$V_L = \pm 20V$, $I_L = 100mA$, $t = 10mS$			5	mA
Recovery Input Current	I_{FOFF}	$V_L = \pm 20V$, $I_L \leq 5uA$	0.2			mA
Detector (Output)						
Output Breakdown Voltage	V_B	$I_B = 50uA$	60			V
Output Off-State Leakage	I_{TOFF}	$V_T = 60V$, $I_F = 0mA$		0.2	1	uA
I/O Capacitance	C_{ISO}	$I_F = 0$, $f = 1MHz$		6		pF
ON Resistance	R_{ON}	$I_L = 100mA$, $I_F = 10mA$		0.83	2.50	Ω
Turn-ON Time	T_{ON}	$I_F = 10mA$, $V_L = \pm 20V$		0.2	1.5	ms
Turn-Off Time	T_{OFF}	$t = 10ms$, $I_L = \pm 100mA$		0.3	1.5	ms

Schematic and Wiring Diagrams

Type	Schematic	Output configuration	Load	Connection	Wiring Diagrams
KAQW212S		2a	AC/DC	-	(1) Two Independent 1 Form A use (2) 2 Form A use

Data Curve

Fig.1 Load current vs. ambient temperature
Allowable ambient temperature:
-40°C to +85°C

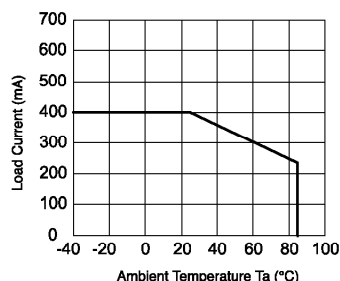


Fig.2 On resistance vs. ambient temperature
Across terminals 5,7 and 6,8 pin
LED current: 5mA
Continuous load current: 400mA(DC)

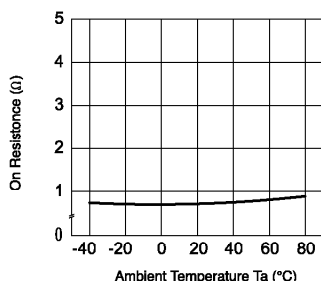


Fig.3 Turn on time vs. ambient temperature
Load voltage: 60V(DC)
LED current: 5mA
Continuous load current: 400mA(DC)

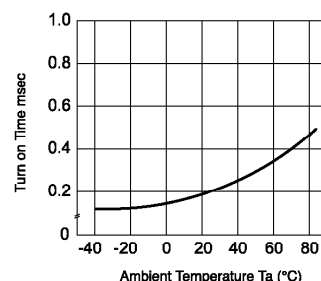


Fig.4 Turn off time vs. ambient temperature
LED current: 5mA; Load voltage:
60V(DC)
Continuous load current: 400mA(DC)

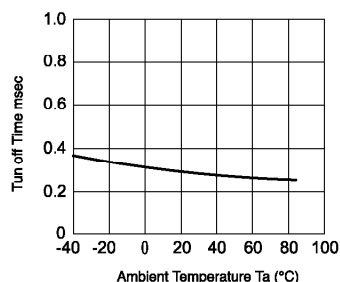


Fig.5 LED operate vs. ambient temperature
Load voltage: 60V(DC)
Continuous load current: 400mA(DC)

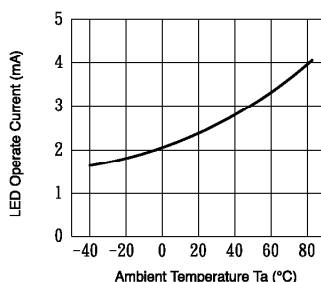


Fig.6 LED turn off current vs. ambient temperature
Load voltage: 60V(DC)
Continuous load current: 400mA(DC)

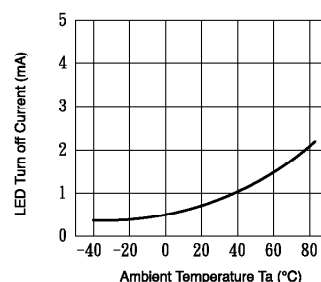


Fig.7 LED dropout voltage vs. ambient temperature
LED current: 5 to 50mA

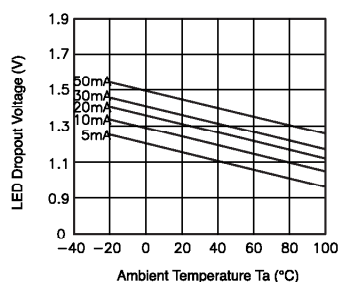


Fig.8 Voltage vs. current characteristics of output at MOS FET portion
Measured portion: across terminals 5,7 and 6,8 pin
Ambient temperature: 25°C

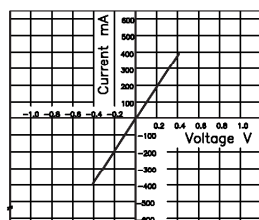


Fig.9 Off state leakage current
Across terminals 5,7 and 6,8 pin
Ambient temperature: 25°C

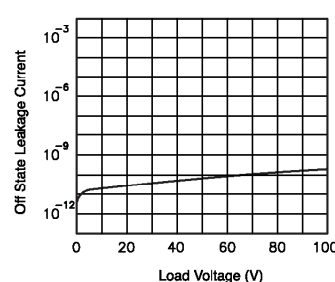


Fig.10 LED forward current vs. turn on time
Across terminals 5,7 and 6,8 pin;
Load voltage: 60V (DC);
Continuous load current: 400mA (DC);
Ambient temperature: 25°C

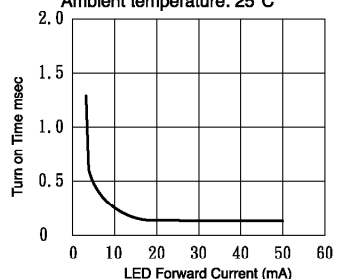


Fig.11 LED forward current vs. turn off time
Across terminals 5,7 and 6,8 pin;
Load voltage: 60V (DC);
Continuous load current: 400mA (DC);
Ambient temperature: 25°C

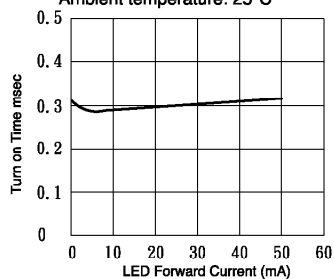


Fig.12 Applied voltage vs. output capacitance
Across terminals 5,7 and 6,8 pin
Frequency: 1MHz
Ambient temperature: 25°C

